

## General Description

The 74HC/HCT153 is a dual 4-input multiplexer. The device features independent enable inputs ( $n\bar{E}$ ) and common data select inputs (S0 and S1). For each multiplexer, the select inputs select one of the four binary inputs and routes it to the multiplexer output ( $nY$ ). A HIGH on  $\bar{E}$  forces the corresponding multiplexer outputs LOW. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

## Features

- Input levels:  
For 74HC153: CMOS level  
For 74HCT153: TTL level
- Non-inverting outputs
- Separate enable input for each output
- Common select inputs
- Permits multiplexing from n lines to 1 line
- Enable line provided for cascading (n lines to 1 line)
- Specified from -40°C to +105°C
- Packaging information: DIP16/SOP16/TSSOP16

## ORDERING INFORMATION

DEVICE	Package Type	MARKING	Packing	Packing QTY
SN74HC153N	DIP-16	74HC153N	Tube	1000/Box
SN74HC153DTR	SOP-16	74HC153	Tape	2500/Reel
SN74HCT153DTR	SOP-16	74HCT153	Tape	2500/Reel
SN74HCT153TDTR	TSSOP-16	74HCT153	Tape	3000/Reel

**Block Diagram And Pin Description**

**Block Diagram**

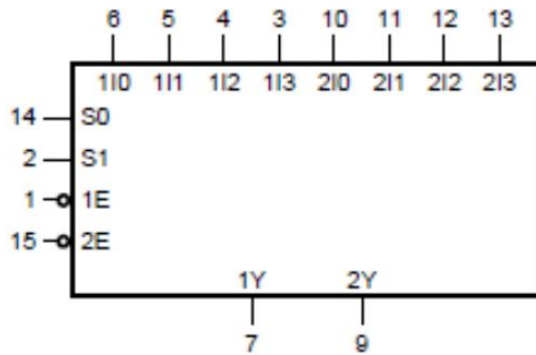


Figure 1. Logic symbol

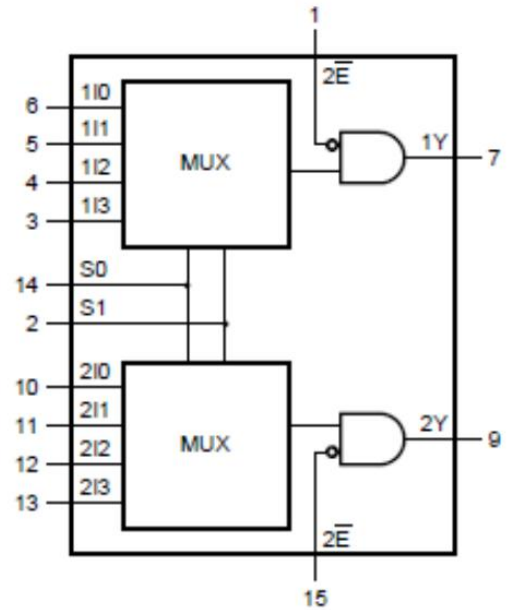


Figure 2. Functional diagram

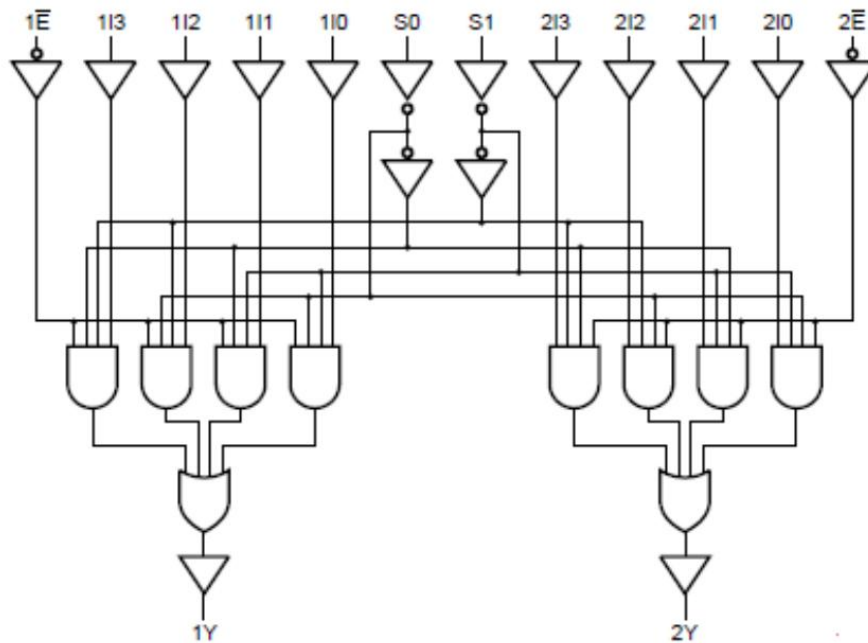
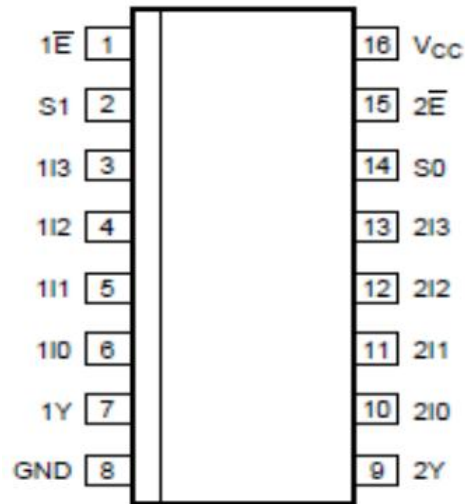


Figure 3. Logic diagram

Pin Configurations



Pin Description

Pin No.	Pin Name	Description
1	1 $\bar{E}$	out enable input(active LOW)
2	S1	data select input
3	1I3	data input source1
4	1I2	data input source1
5	1I1	data input source1
6	1I0	data input source1
7	1Y	multiplexer output source1
8	GND	ground(0V)
9	2Y	multiplexer output source2
10	2I0	data input source2
11	2I1	data input source2
12	2I2	data input source2
13	2I3	data input source2
14	S0	data select input
15	2 $\bar{E}$	out enable input(active LOW)
16	V <sub>CC</sub>	supply voltage

Function Table

Select Input		Input				Output Enable	Output
S0	S1	nI0	nI1	nI2	nI3	n $\bar{E}$	nY
X	X	X	X	X	X	H	L
L	L	L	X	X	X	L	L
L	L	H	X	X	X	L	H
H	L	X	L	X	X	L	L
H	L	X	H	X	X	L	H
L	H	X	X	L	X	L	L
L	H	X	X	H	X	L	H
H	H	X	X	X	L	L	L
H	H	X	X	X	H	L	H

Note: H=HIGH voltage level; L=LOW voltage level; X=don't care.

## Electrical Parameter

**Absolute Maximum Ratings** (Voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Max.	Unit
supply voltage	V <sub>CC</sub>	-	-0.5	+7.0	V
input clamping current	I <sub>IK</sub>	V <sub>I</sub> < -0.5V or V <sub>I</sub> > V <sub>CC</sub> +0.5V	-	±20	mA
output clamping current	I <sub>OK</sub>	V <sub>O</sub> < -0.5V or V <sub>O</sub> > V <sub>CC</sub> +0.5V	-	±20	mA
output current	I <sub>O</sub>	-0.5V < V <sub>O</sub> < V <sub>CC</sub> +0.5V	-	±25	mA
supply current	I <sub>CC</sub>	-	-	50	mA
ground current	I <sub>GND</sub>	-	-50	-	mA
storage temperature	T <sub>stg</sub>	-	-65	+150	°C
total power dissipation	P <sub>tot</sub>	-	-	500	mW
soldering temperature	T <sub>L</sub>	10s	DIP	245	°C
			SOP	250	

Note:

[1] For DIP16 packages: above 70°C the value of P<sub>tot</sub> derates linearly with 12mW/K.

[2] For SOP16 packages: above 70°C the value of P<sub>tot</sub> derates linearly with 8mW/K.

[3] For (T)SSOP16 packages: above 60°C the value of P<sub>tot</sub> derates linearly with 5.5mW/K.

Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
<b>74HC153</b>						
supply voltage	V <sub>CC</sub>	-	2.0	5.0	6.0	V
input voltage	V <sub>I</sub>	-	0	-	V <sub>CC</sub>	V
output voltage	V <sub>O</sub>	-	0	-	V <sub>CC</sub>	V
input transition rise and fall rate	$\Delta t/\Delta V$	V <sub>CC</sub> =2.0V	-	-	625	ns/V
		V <sub>CC</sub> =4.5V	-	1.67	139	ns/V
		V <sub>CC</sub> =6.0V	-	-	83	ns/V
ambient temperature	T <sub>amb</sub>	-	-40	-	+105	°C
<b>74HCT153</b>						
supply voltage	V <sub>CC</sub>	-	4.5	5.0	5.5	V
input voltage	V <sub>I</sub>	-	0	-	V <sub>CC</sub>	V
output voltage	V <sub>O</sub>	-	0	-	V <sub>CC</sub>	V
input transition rise and fall rate	$\Delta t/\Delta V$	V <sub>CC</sub> =4.5V	-	1.67	139	ns/V
ambient temperature	T <sub>amb</sub>	-	-40	-	+105	°C

**Electrical Characteristics**

DC Characteristics 1 (T<sub>amb</sub>=25°C, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
<b>74HC153</b>							
HIGH-level input voltage	V <sub>IH</sub>	V <sub>CC</sub> =2.0V	1.5	1.2	-	V	
		V <sub>CC</sub> =4.5V	3.15	2.4	-	V	
		V <sub>CC</sub> =6.0V	4.2	3.2	-	V	
LOW-level input voltage	V <sub>IL</sub>	V <sub>CC</sub> =2.0V	-	0.8	0.5	V	
		V <sub>CC</sub> =4.5V	-	2.1	1.35	V	
		V <sub>CC</sub> =6.0V	-	2.8	1.8	V	
HIGH-level output voltage	V <sub>OH</sub>	V <sub>I</sub> =V <sub>IH</sub> or V <sub>IL</sub>	I <sub>O</sub> =-20uA; V <sub>CC</sub> =2.0V	1.9	2.0	-	V
			I <sub>O</sub> =-20uA; V <sub>CC</sub> =4.5V	4.4	4.5	-	V
			I <sub>O</sub> =-20uA; V <sub>CC</sub> =6.0V	5.9	6.0	-	V
			I <sub>O</sub> =-4.0mA; V <sub>CC</sub> =4.5V	3.98	4.32	-	V
			I <sub>O</sub> =-5.2mA; V <sub>CC</sub> =6.0V	5.48	5.81	-	V
LOW-level output voltage	V <sub>OL</sub>	V <sub>I</sub> =V <sub>IH</sub> or V <sub>IL</sub>	I <sub>O</sub> =20uA; V <sub>CC</sub> =2.0V	-	0	0.1	V
			I <sub>O</sub> =20uA; V <sub>CC</sub> =4.5V	-	0	0.1	V
			I <sub>O</sub> =20uA; V <sub>CC</sub> =6.0V	-	0	0.1	V
			I <sub>O</sub> =4.0mA; V <sub>CC</sub> =4.5V	-	0.15	0.26	V
			I <sub>O</sub> =5.2mA; V <sub>CC</sub> =6.0V	-	0.16	0.26	V
input leakage current	I <sub>I</sub>	V <sub>I</sub> =V <sub>CC</sub> or GND; V <sub>CC</sub> =6.0V	-	-	±0.1	μA	

supply current	$I_{CC}$	$V_I=V_{CC}$ or GND; $I_O=0A$ ; $V_{CC}=6.0V$	-	-	8.0	$\mu A$	
input apacitance	$C_I$	-	-	3.5	-	pF	
<b>74HCT153</b>							
HIGH-level input voltage	$V_{IH}$	$V_{CC}=4.5V$ to 5.5V	2.0	1.6	-	V	
LOW-level input voltage	$V_{IL}$	$V_{CC}=4.5V$ to 5.5V	-	1.2	0.8	V	
HIGH-level output voltage	$V_{OH}$	$V_I=V_{IH}$ or $V_{IL}$ $V_{CC}=4.5V$	$I_O=-20\mu A$	4.4	4.5	-	V
			$I_O=-4.0\mu A$	3.98	4.32	-	V
LOW-level output voltage	$V_{OL}$	$V_I=V_{IH}$ or $V_{IL}$	$I_O=20\mu A$ ; $V_{CC}=4.5V$	-	0	0.1	V
			$I_O=5.2\mu A$ ; $V_{CC}=6.0V$	-	0.15	0.26	V
input leakage current	$I_I$	$V_I=V_{CC}$ or GND; $V_{CC}=5.5V$	-	-	$\pm 0.1$	$\mu A$	
supply current	$I_{CC}$	$V_I=V_{CC}$ or GND; $I_O=0A$ ; $V_{CC}=5.5V$	-	-	8.0	$\mu A$	
Additional Supply current	$\Delta I_{CC}$	$V_I=V_{CC}-2.1V$ ; other inputs at $V_{CC}$ or GND; $I_O=0V$ ; $V_{CC}=4.5V$ to 5.5V	1In,2In	-	45	162	$\mu A$
			$n\bar{E}$	-	60	216	$\mu A$
			Sn	-	135	486	$\mu A$
input apacitance	$C_I$	-	-	3.5	-	pF	

## DC Characteristics 2

( $T_{amb}=-40^{\circ}C$  to  $+85^{\circ}C$ , voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
<b>74HC153</b>							
HIGH-level input voltage	$V_{IH}$	$V_{CC}=2.0V$	1.5	-	-	V	
		$V_{CC}=4.5V$	3.15	-	-	V	
		$V_{CC}=6.0V$	4.2	-	-	V	
LOW-level input voltage	$V_{IL}$	$V_{CC}=2.0V$	-	-	0.5	V	
		$V_{CC}=4.5V$	-	-	1.35	V	
		$V_{CC}=6.0V$	-	-	1.8	V	
HIGH-level output voltage	$V_{OH}$	$V_I=V_{IH}$ or $V_{IL}$	$I_O=-20\mu A$ ; $V_{CC}=2.0V$	1.9	-	-	V
			$I_O=-20\mu A$ ; $V_{CC}=4.5V$	4.4	-	-	V
			$I_O=-20\mu A$ ; $V_{CC}=6.0V$	5.9	-	-	V
			$I_O=-4.0mA$ ; $V_{CC}=4.5V$	3.84	-	-	V
			$I_O=-5.2mA$ ; $V_{CC}=6.0V$	5.34	-	-	V
LOW-level output voltage	$V_{OL}$	$V_I=V_{IH}$ or $V_{IL}$	$I_O=20\mu A$ ; $V_{CC}=2.0V$	-	-	0.1	V
			$I_O=20\mu A$ ; $V_{CC}=4.5V$	-	-	0.1	V
			$I_O=20\mu A$ ; $V_{CC}=6.0V$	-	-	0.1	V
			$I_O=4.0mA$ ; $V_{CC}=4.5V$	-	-	0.33	V
			$I_O=5.2mA$ ; $V_{CC}=6.0V$	-	-	0.33	V
input leakage current	$I_I$	$V_i=V_{CC}$ or GND; $V_{CC}=6.0V$	-	-	$\pm 1.0$	$\mu A$	

supply current	$I_{CC}$	$V_i=V_{CC}$ or GND; $I_o=0A$ ; $V_{CC}=6.0V$		-	-	80	$\mu A$
<b>74HCT153</b>							
HIGH-level input voltage	$V_{IH}$	$V_{CC}=4.5V$ to $5.5V$		2.0	-	-	V
LOW-level input voltage	$V_{IL}$	$V_{CC}=4.5V$ to $5.5V$		-	-	0.8	V
HIGH-level output voltage	$V_{OH}$	$V_I=V_{IH}$ or $V_{IL}$ $V_{CC}=4.5V$	$I_o=-20\mu A$	4.4	-	-	V
			$I_o=-4.0mA$	3.84	-	-	V
LOW-level output voltage	$V_{OL}$	$V_I=V_{IH}$ or $V_{IL}$	$I_o=20\mu A$ ; $V_{CC}=4.5V$	-	-	0.1	V
			$I_o=5.2mA$ ; $V_{CC}=6.0V$	-	-	0.33	V
input leakage current	$I_I$	$V_i=V_{CC}$ or GND; $V_{CC}=5.5V$		-	-	$\pm 1.0$	$\mu A$
supply current	$I_{CC}$	$V_i=V_{CC}$ or GND; $I_o=0A$ ; $V_{CC}=5.5V$		-	-	80	$\mu A$
additional supply current	$\Delta I_{CC}$	$V_i=V_{CC}-2.1V$ ; other inputs at $V_{CC}$ or GND; $I_o=0V$ ; $V_{CC}=4.5V$ to $5.5V$	$1I_n, 2I_n$	-	-	203	$\mu A$
			$n\bar{E}$	-	-	270	$\mu A$
			$S_n$	-	-	608	$\mu A$

### DC Characteristics 3

( $T_{amb}=-40^{\circ}C$  to  $+105^{\circ}C$ , voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
<b>74HC153</b>							
HIGH-level input voltage	$V_{IH}$	$V_{CC}=2.0V$	1.5	-	-	V	
		$V_{CC}=4.5V$	3.15	-	-	V	
		$V_{CC}=6.0V$	4.2	-	-	V	
LOW-level input voltage	$V_{IL}$	$V_{CC}=2.0V$	-	-	0.5	V	
		$V_{CC}=4.5V$	-	-	1.35	V	
		$V_{CC}=6.0V$	-	-	1.8	V	
HIGH-level output voltage	$V_{OH}$	$V_I=V_{IH}$ or $V_{IL}$	$I_o=-20\mu A$ ; $V_{CC}=2.0V$	1.9	-	-	V
			$I_o=-20\mu A$ ; $V_{CC}=4.5V$	4.4	-	-	V
			$I_o=-20\mu A$ ; $V_{CC}=6.0V$	5.9	-	-	V
			$I_o=-4.0mA$ ; $V_{CC}=4.5V$	3.7	-	-	V
			$I_o=-5.2mA$ ; $V_{CC}=6.0V$	5.2	-	-	V
LOW-level output voltage	$V_{OL}$	$V_I=V_{IH}$ or $V_{IL}$	$I_o=20\mu A$ ; $V_{CC}=2.0V$	-	-	0.1	V
			$I_o=20\mu A$ ; $V_{CC}=4.5V$	-	-	0.1	V
			$I_o=20\mu A$ ; $V_{CC}=6.0V$	-	-	0.1	V
			$I_o=4.0mA$ ; $V_{CC}=4.5V$	-	-	0.4	V
			$I_o=5.2mA$ ; $V_{CC}=6.0V$	-	-	0.4	V

input leakage current	$I_I$	$V_I = V_{CC}$ or GND; $V_{CC}=6.0V$	-	-	$\pm 1.0$	$\mu A$	
supply current	$I_{CC}$	$V_I=V_{CC}$ or GND; $I_O=0A$ ; $V_{CC}=6.0V$	-	-	160	$\mu A$	
<b>74HCT153</b>							
HIGH-level input voltage	$V_{IH}$	$V_{CC}=4.5V$ to 5.5V	2.0	-	-	V	
LOW-level input voltage	$V_{IL}$	$V_{CC}=4.5V$ to 5.5V	-	-	0.8	V	
HIGH-level output voltage	$V_{OH}$	$V_I=V_{IH}$ or $V_{IL}$ $V_{CC}=4.5V$	$I_O=-20\mu A$	4.4	-	-	V
			$I_O=-4.0mA$	3.7	-	-	V
LOW-level output voltage	$V_{OL}$	$V_I=V_{IH}$ or $V_{IL}$	$I_O=20\mu A$ ; $V_{CC}=4.5V$	-	-	0.1	V
			$I_O=5.2\mu A$ ; $V_{CC}=6.0V$	-	-	0.4	V
input leakage current	$I_I$	$V_I = V_{CC}$ or GND; $V_{CC}=5.5V$	-	-	$\pm 1.0$	$\mu A$	
supply current	$I_{CC}$	$V_I=V_{CC}$ or GND; $I_O=0A$ ; $V_{CC}=5.5V$	-	-	160	$\mu A$	
additional supply current	$\Delta I_{CC}$	$V_I=V_{CC}-2.1V$ ; other inputs at $V_{CC}$ or GND; $I_O=0V$ ; $V_{CC}=4.5V$ to 5.5V	1In, 2In	-	-	221	$\mu A$
			$n\bar{E}$	-	-	294	$\mu A$
			Sn	-	-	662	$\mu A$

AC Characteristics 1 (Tamb=25°C, GND =0V;  $t_r=t_f=6ns$ ;  $C_L=50pF$ , unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
<b>74HC153</b>							
Propagation delay	$t_{pd}$	1In to nY, 2In to nY; see Figure5 <sup>[1]</sup>	$V_{CC}=2.0V$	-	47	145	ns
			$V_{CC}=4.5V$	-	17	29	ns
			$V_{CC}=5.0V$ ; $C_L=15pF$	-	14	-	ns
			$V_{CC}=6.0V$	-	14	25	ns
		Sn to nY; see Figure6	$V_{CC}=2.0V$	-	50	150	ns
			$V_{CC}=4.5V$	-	18	30	ns
			$V_{CC}=5.0V$ ; $C_L=15pF$	-	15	-	ns
			$V_{CC}=6.0V$	-	14	26	ns
		$n\bar{E}$ to nY see Figure6	$V_{CC}=2.0V$	-	33	100	ns
			$V_{CC}=4.5V$	-	12	20	ns
			$V_{CC}=5.0V$ ; $C_L=15pF$	-	10	-	ns
			$V_{CC}=6.0V$	-	10	17	ns
transition time	$t_t$	see Figure5 <sup>[2]</sup>	$V_{CC}=2.0V$	-	19	75	ns
			$V_{CC}=4.5V$	-	7	15	ns
			$V_{CC}=6.0V$	-	6	13	ns
power dissipation capacitance	$C_{PD}$	per package; $V_I=GND$ to $V_{CC}$ <sup>[3]</sup>	-	30	-	pF	



74HCT153							
HIGH to LOW propagation delay	$t_{PHL}$	1In to nY,2In to nY; see Figure5 <sup>[1]</sup>	$V_{CC}=4.5V$	-	19	34	ns
			$V_{CC}=5.0V;C_L=15pF$	-	16	-	ns
LOW to HIGH propagation delay	$t_{PLH}$	1In to nY,2In to nY; see Figure5	$V_{CC}=4.5V$	-	13	24	ns
			$V_{CC}=5.0V;C_L=15pF$	-	16	-	ns
Propagation delay	$t_{pd}$	Sn to nY see Figure6	$V_{CC}=4.5V$	-	20	34	ns
			$V_{CC}=5.0V;C_L=15pF$	-	17	-	ns
		n $\bar{E}$ to nY see Figure6	$V_{CC}=4.5V$	-	14	27	ns
			$V_{CC}=5.0V;C_L=15pF$	-	11	-	ns
transition time	$t_t$	$V_{CC}=4.5V$ ;see Figure5 <sup>[2]</sup>		-	7	15	ns
power dissipation capacitance	$C_{PD}$	per package; $V_I=GND$ to $V_{CC}-1.5V$ <sup>[3]</sup>		-	30	-	pF

Note:

[1] $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[2] $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

[3] $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in uW).

$$P_D=C_{PD}\times V_{CC}^2\times f_i\times N+\sum(C_L\times V_{CC}^2\times f_o)$$
 where:

$f_i$ =input frequency in MHz;

$f_o$ =output frequency in MHz;

$C_L$ =output load capacitance in pF;

$V_{CC}$ =supply voltage in V;

$N$ =number of inputs switching;

$\sum(C_L\times V_{CC}^2\times f)$ =sum of outputs.

**AC Characteristics 2** ( $T_{amb}=-40^\circ C$  to  $+85^\circ C$ ,  $GND=0V$ ;  $t_r=t_f=6ns$ ;  $C_L=50pF$ , unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
<b>74HC153</b>							
Propagation delay	$t_{pd}$	1In to nY,2In to nY; see Figure5 <sup>[1]</sup>	$V_{CC}=2.0V$	-	-	180	ns
			$V_{CC}=4.5V$	-	-	36	ns
			$V_{CC}=6.0V$	-	-	31	ns
		Sn to nY; see Figure6	$V_{CC}=2.0V$	-	-	190	ns
			$V_{CC}=4.5V$	-	-	38	ns
			$V_{CC}=6.0V$	-	-	33	ns
		n $\bar{E}$ to nY see Figure6	$V_{CC}=2.0V$	-	-	125	ns
			$V_{CC}=4.5V$	-	-	25	ns
			$V_{CC}=6.0V$	-	-	21	ns

transition time	$t_t$	see Figure5 <sup>[2]</sup>	$V_{CC}=2.0V$	-	-	95	ns
			$V_{CC}=4.5V$	-	-	19	ns
			$V_{CC}=6.0V$	-	-	16	ns
<b>74HCT153</b>							
HIGH to LOW propagation delay	$t_{PHL}$	1In to nY,2In to nY; see Figure5 <sup>[1]</sup>	$V_{CC}=4.5V$	-	-	43	ns
LOW to HIGH propagation delay	$t_{PLH}$	1In to nY,2In to nY; see Figure5	$V_{CC}=4.5V$	-	-	30	ns
Propagation delay	$t_{pd}$	Sn to nY see Figure6	$V_{CC}=4.5V$	-	-	43	ns
		$n\bar{E}$ to nY see Figure6	$V_{CC}=4.5V$	-	-	34	ns
transition time	$t_t$	$V_{CC}=4.5V$ ;see Figure5 <sup>[2]</sup>		-	-	19	ns

Note:

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

**AC Characteristics 3** ( $T_{amb}=-40^{\circ}C$  to  $+105^{\circ}C$ ,  $GND=0V$ ;  $t_r=t_f=6ns$ ;  $C_L=50pF$ , unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
<b>74HC153</b>							
Propagation delay	$t_{pd}$	1In to nY,2In to nY; see Figure5 <sup>[1]</sup>	$V_{CC}=2.0V$	-	-	220	ns
			$V_{CC}=4.5V$	-	-	44	ns
			$V_{CC}=6.0V$	-	-	38	ns
		Sn to nY; see Figure6	$V_{CC}=2.0V$	-	-	225	ns
			$V_{CC}=4.5V$	-	-	45	ns
			$V_{CC}=6.0V$	-	-	38	ns
		$n\bar{E}$ to nY see Figure6	$V_{CC}=2.0V$	-	-	150	ns
			$V_{CC}=4.5V$	-	-	30	ns
			$V_{CC}=6.0V$	-	-	26	ns
transition time	$t_t$	see Figure5 <sup>[2]</sup>	$V_{CC}=2.0V$	-	-	110	ns
			$V_{CC}=4.5V$	-	-	22	ns
			$V_{CC}=6.0V$	-	-	19	ns
<b>74HCT153</b>							
HIGH to LOW propagation delay	$t_{PHL}$	1In to nY,2In to nY; see Figure5 <sup>[1]</sup>	$V_{CC}=4.5V$	-	-	51	ns
LOW to HIGH propagation delay	$t_{PLH}$	1In to nY,2In to nY; see Figure5	$V_{CC}=4.5V$	-	-	36	ns
Propagation delay	$t_{pd}$	Sn to nY see Figure6	$V_{CC}=4.5V$	-	-	51	ns
		$n\bar{E}$ to nY	$V_{CC}=4.5V$	-	-	41	ns

		see Figure6				
transition time	$t_t$	$V_{CC}=4.5V$ ; see Figure5 <sup>[2]</sup>		-	-	22 ns

Note:

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

## Testing Circuit

### AC Testing Circuit

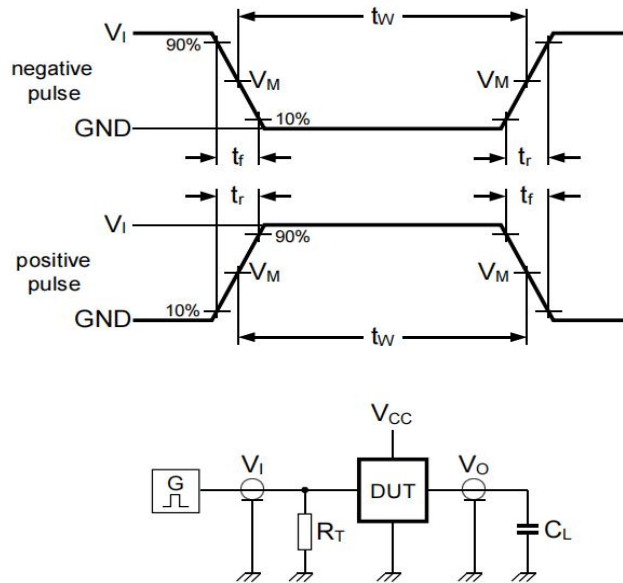


Figure 4. Test circuit for measuring switching times

Definitions for test circuit:

$C_L$ =Load capacitance including jig and probe capacitance.

$R_T$ =Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

AC Testing Waveforms

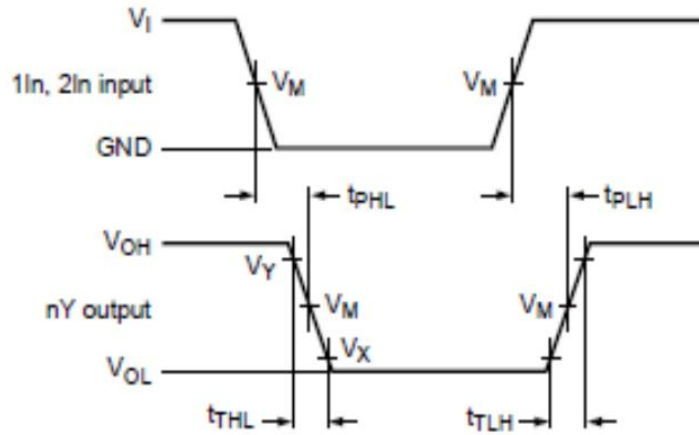


Figure 5. Waveforms showing the input (1In, 2In) to output (1Y, 2Y) propagation delays and output transition times

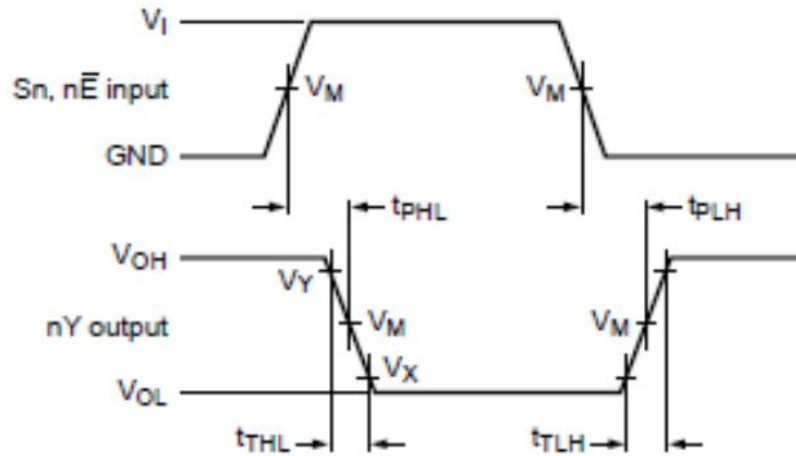


Figure 6. Waveforms showing input (Sn, nE) to output (nY) propagation delays

Measurement Points

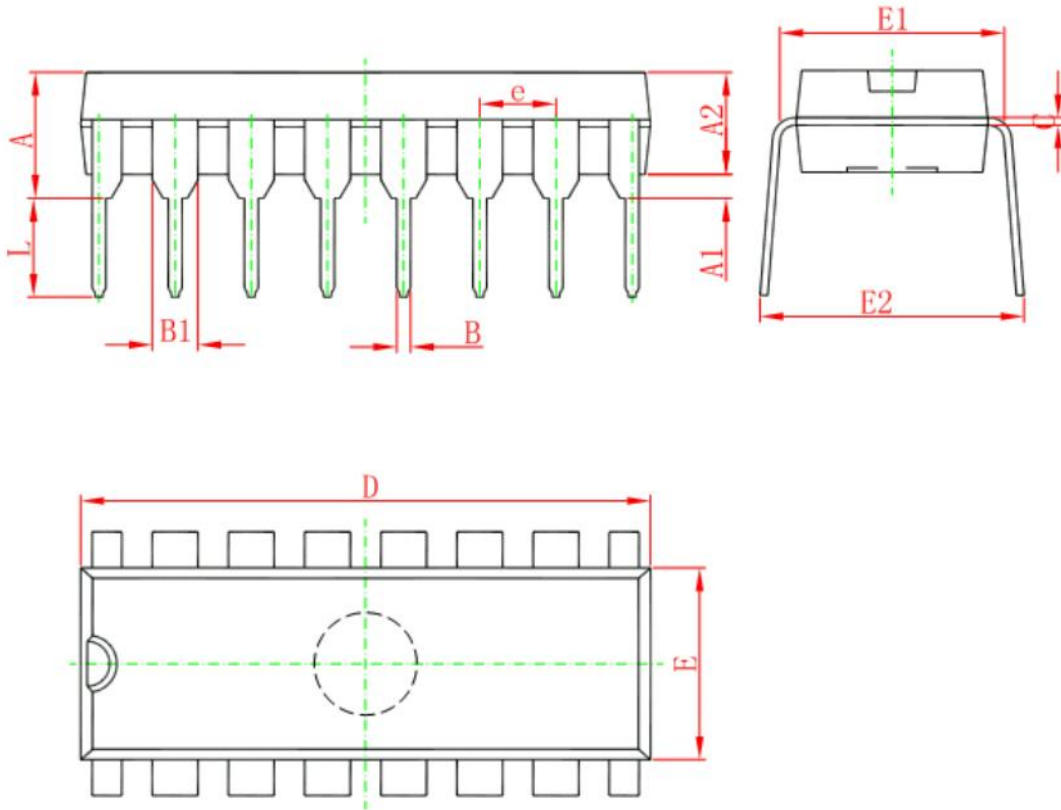
Type	Input	Output		
	$V_M$	$V_M$	$V_X$	$V_Y$
74HC153	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$
74HCT153	1.3V	1.3V	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$

Test Data

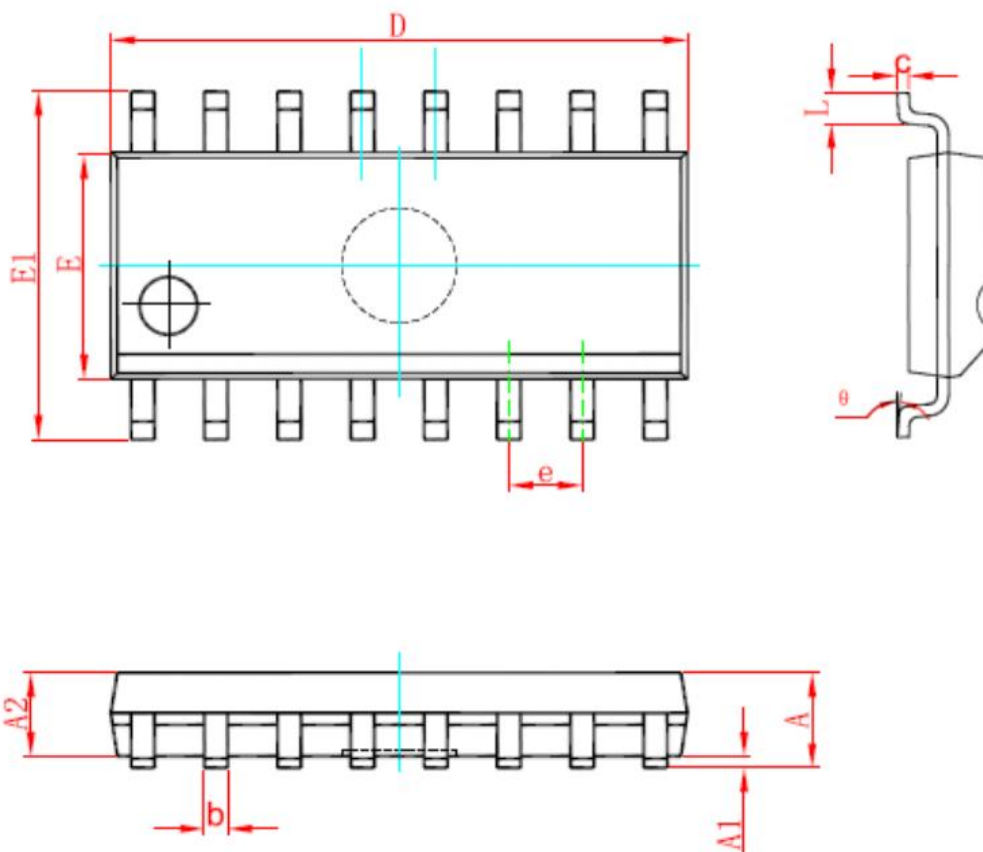
Type	Input		Load	Test
	$V_I$	$t_r, t_f$	$C_L$	
74HC153	$V_{CC}$	6.0ns	15pF, 50pF	$t_{PHL}, t_{PLH}$
74HCT153	3.0V	6.0ns	15pF, 50pF	$t_{PHL}, t_{PLH}$

Package Information

DIP16

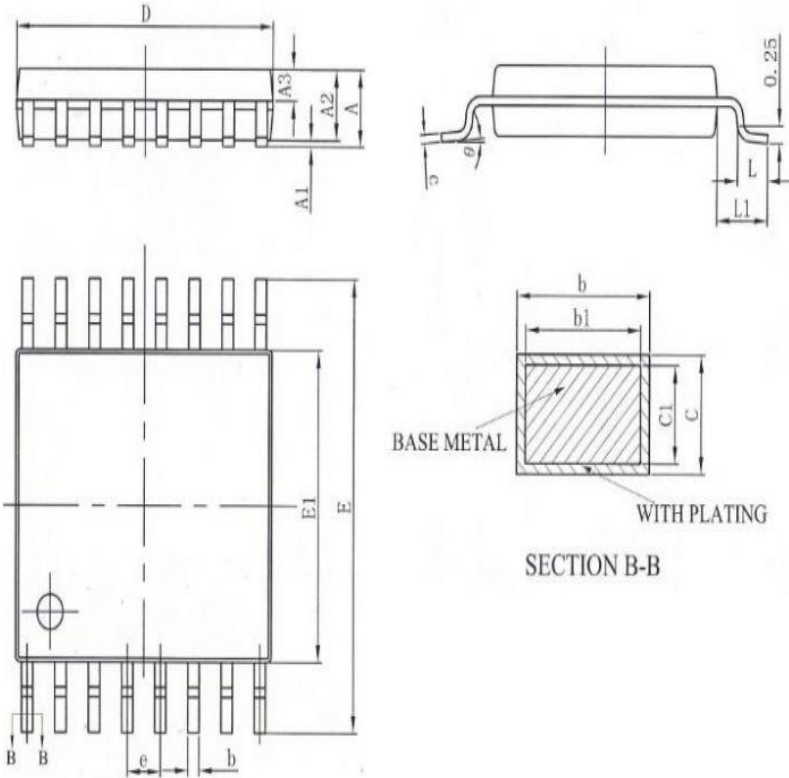


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.710	4.310	0.146	0.170
A1	0.510		0.020	
A2	3.200	3.600	0.126	0.142
B	0.380	0.570	0.015	0.022
B1	1.524(BSC)		0.060(BSC)	
C	0.204	0.360	0.008	0.014
D	18.800	19.200	0.740	0.756
E	6.200	6.600	0.244	0.260
E1	7.320	7.920	0.288	0.312
e	2.540(BSC)		0.100(BSC)	
L	3.000	3.600	0.118	0.142
E2	8.400	9.000	0.331	0.354



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
C	0.170	0.250	0.007	0.010
D	9.800	10.200	0.386	0.402
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

TSSOP16



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	-	-	1.20
A1	0.05	-	0.15
A2	0.90	1.00	1.05
A3	0.39	0.44	0.49
b	0.20	-	0.28
b1	0.19	0.22	0.25
c	0.13	-	0.17
cl	0.12	0.13	0.14
D	4.90	5.00	5.10
E	6.20	6.40	6.60
E1	4.30	4.40	4.50
e	0.65BSC		
L	0.45	0.60	0.75
L1	1.00BSC		
θ	0	-	8°

Statements And Notes

Part name	Hazardous substances or Elements									
	Lead and lead compounds	Mercury and mercury compounds	Cadmium and cadmium compounds	Hexavalent chromium compounds	Polybrominated biphenyls	Polybrominated biphenyl ethers	Dibutyl phthalate	Butyl benzyl phthalate	Di-2-ethylhexyl phthalate	Diisobutyl phthalate
Lead frame	○	○	○	○	○	○	○	○	○	○
Plastic resin	○	○	○	○	○	○	○	○	○	○
Chip	○	○	○	○	○	○	○	○	○	○
The lead	○	○	○	○	○	○	○	○	○	○
Plastic sheet installed	○	○	○	○	○	○	○	○	○	○
explanation	○: Indicates that the content of hazardous substances or elements in the detection limit of the following the SJ/T11363-2006 standard. ×: Indicates that the content of hazardous substances or elements exceeding the SJ/T11363-2006 Standard limit requirements									

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